

## General Features

- High Power and Current Handling Capability
- Lead Free Product is Acquired
- Surface Mount Package

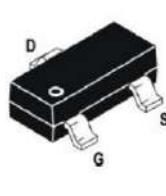
## Application

- Battery Protection
- Load Switch
- Power Management

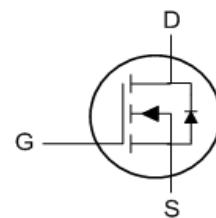
## Product Summary



$V_{DS}$	60	V
$R_{DS(on),TYP} @ V_{GS}=10\text{ V}$	100	$\text{m}\Omega$
$I_d$	3	A



SOT23



N-Channel

## Absolute Maximum Ratings ( $T_c=25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter		Max.	Units
$V_{DSS}$	Drain-Source Voltage		60	V
$V_{GSS}$	Gate-Source Voltage		$\pm 20$	V
$I_d$	Continuous Drain Current	$T_c = 25^\circ\text{C}$	3	A
		$T_c = 100^\circ\text{C}$	2	
$I_{DM}$	Pulsed Drain Current <sup>note1</sup>		10	A
$P_D$	Power Dissipation	$T_A = 25^\circ\text{C}$	0.35	W
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient		357	$^\circ\text{C}/\text{W}$
$T_J, T_{STG}$	Operating and Storage Temperature Range		-55 to +150	$^\circ\text{C}$

**Electrical Characteristics** ( $T_c=25^\circ\text{C}$  unless otherwise specified)

Symbol	Parameter	Test Condition	Min.	Typ.	Max.	Units
<b>Off Characteristic</b>						
$V_{(\text{BR})\text{DSS}}$	Drain-Source Breakdown Voltage	$V_{GS}=0\text{V}, I_D = 250\mu\text{A}$	60	-	-	V
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{DS} = 48\text{V}, V_{GS} = 0\text{V},$	-	-	1	$\mu\text{A}$
$I_{GSS}$	Gate to Body Leakage Current	$V_{DS} = 0\text{V}, V_{GS} = \pm 20\text{V}$	-	-	$\pm 100$	nA
<b>On Characteristics</b>						
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250\mu\text{A}$	1.0	-	2.5	V
$R_{DS(\text{on})}$ note2	Static Drain-Source on-Resistance	$V_{GS} = 10\text{V}, I_D = 2\text{A}$	-	-	100	$\text{m}\Omega$
		$V_{GS} = 4.5\text{V}, I_D = 1\text{A}$	-	-	110	
<b>Dynamic Characteristics</b>						
$C_{iss}$	Input Capacitance	$V_{DS} = 30\text{V}, V_{GS} = 0\text{V}, f = 1.0\text{MHz}$	-	250	-	pF
$C_{oss}$	Output Capacitance		-	26	-	pF
$C_{rss}$	Reverse Transfer Capacitance		-	20	-	pF
$Q_g$	Total Gate Charge	$V_{DS} = 30\text{V}, I_D = 3\text{A}, V_{GS} = 4.5\text{V}$	-	7	-	nC
$Q_{gs}$	Gate-Source Charge		-	1.2	-	nC
$Q_{gd}$	Gate-Drain("Miller") Charge		-	1.5	-	nC
<b>Switching Characteristics</b>						
$t_{d(on)}$	Turn-on Delay Time	$V_{DD} = 30\text{V}, I_D = 1.5\text{A}, R_{\text{GEN}} = 1\Omega, V_{GS} = 10\text{V}$	-	6.5	-	ns
$t_r$	Turn-on Rise Time		-	15.2	-	ns
$t_{d(off)}$	Turn-off Delay Time		-	15.2	-	ns
$t_f$	Turn-off Fall Time		-	10.3	-	ns
<b>Drain-Source Diode Characteristics and Maximum Ratings</b>						
$I_s$	Maximum Continuous Drain to Source Diode Forward Current	-	-	3	A	
$I_{sm}$	Maximum Pulsed Drain to Source Diode Forward Current	-	-	10	A	
$V_{SD}$	Drain to Source Diode Forward Voltage	$V_{GS}=0\text{V}, I_s = 1\text{A}$	-	-	1.2	V

Notes:1. Repetitive Rating: Pulse Width Limited by Maximum Junction Temperature

2. Pulse Test: Pulse Width $\leq 300\mu\text{s}$ , Duty Cycle $\leq 0.5\%$

## Typical Performance Characteristics

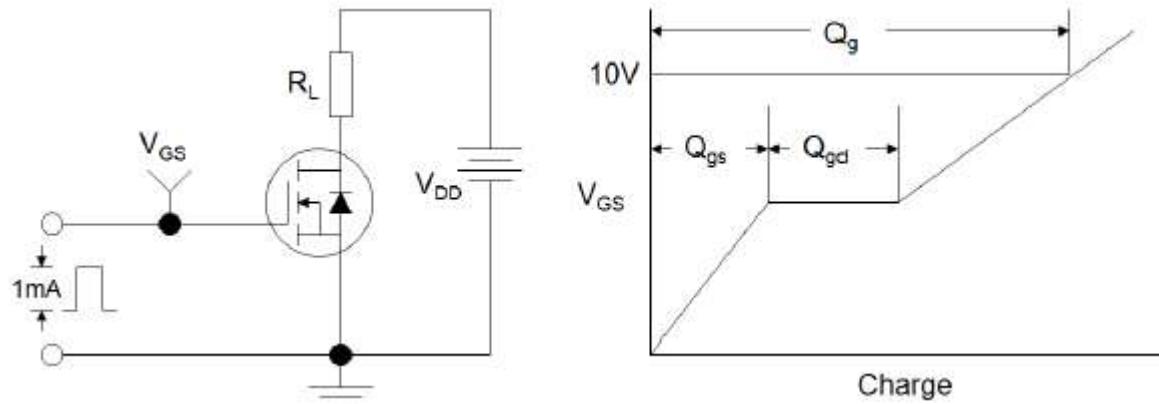


Figure1:Gate Charge Test Circuit & Waveform

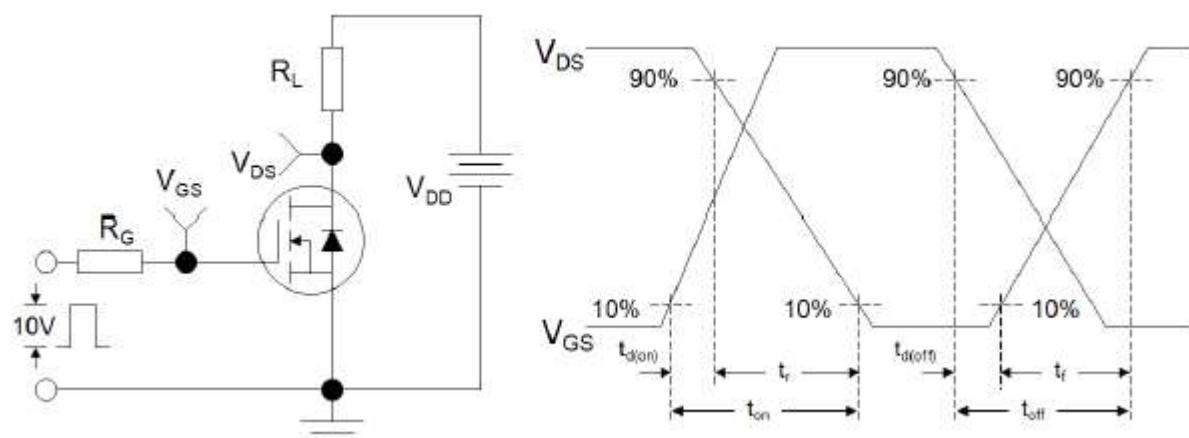


Figure 2: Resistive Switching Test Circuit & Waveforms

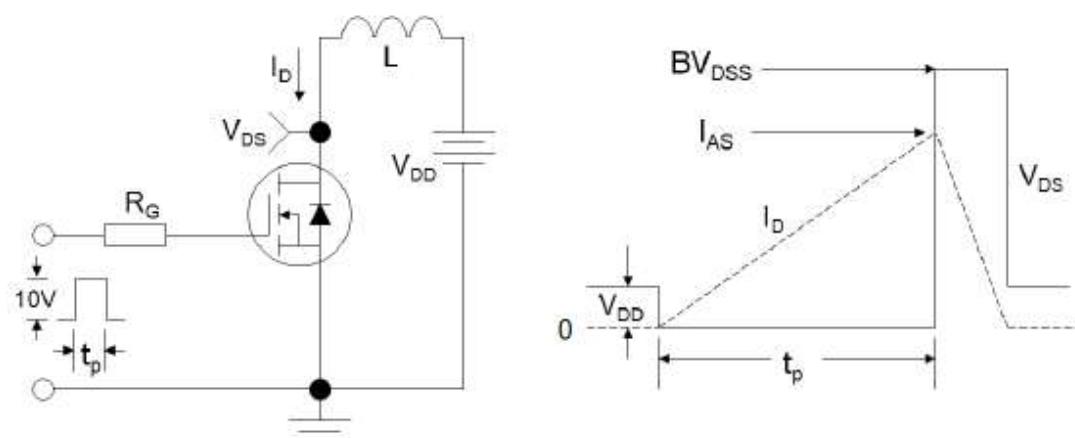


Figure 3:Unclamped Inductive Switching Test Circuit & Waveforms

### Typical Electrical and Thermal Characteristics (Curves)

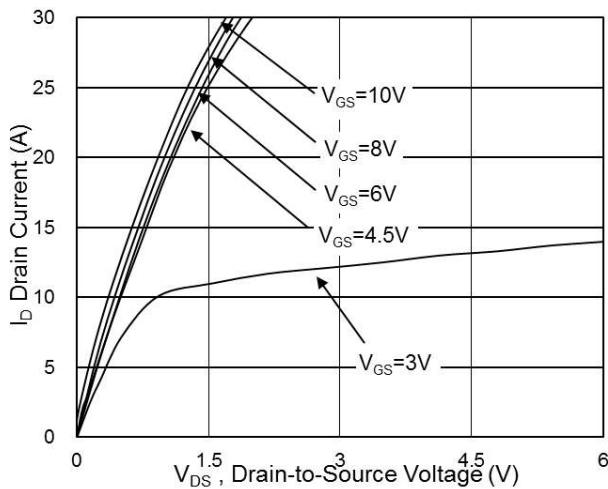


Fig.1 Typical Output Characteristics

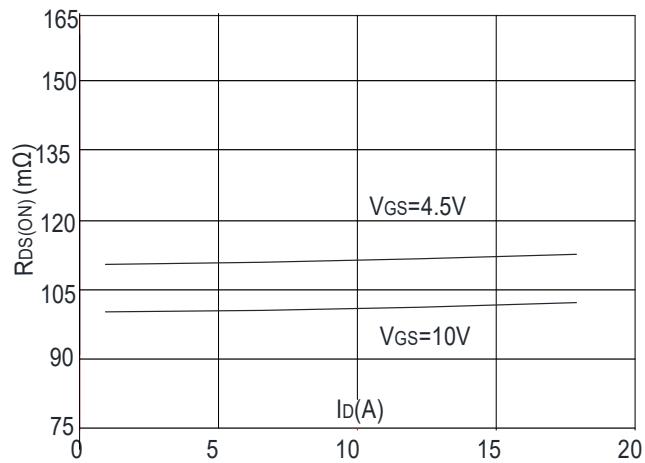


Fig.2 On-Resistance vs Drain Current

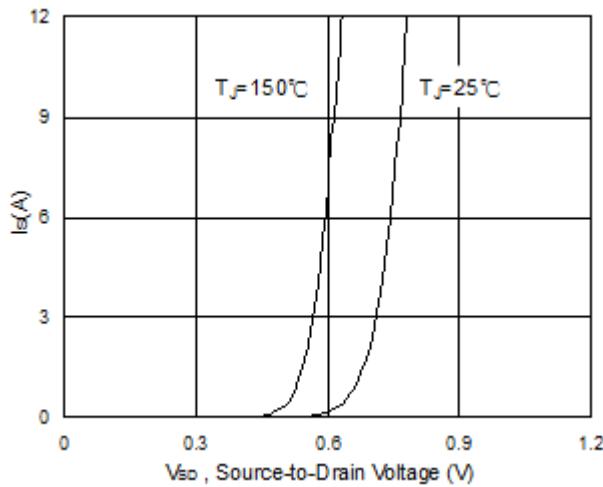


Fig.3 Source Drain Forward Characteristics

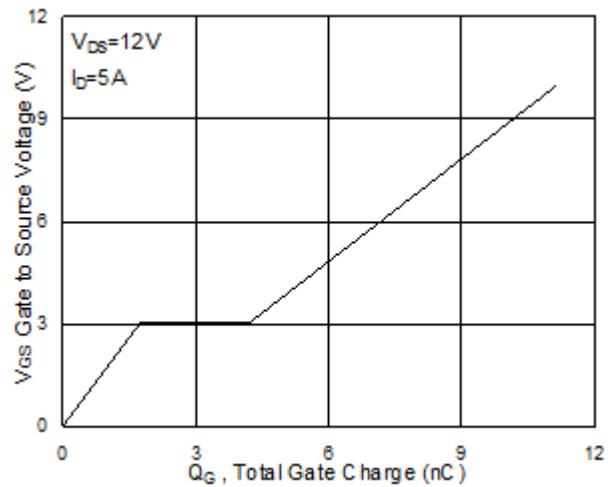


Fig.4 Gate-Charge Characteristics

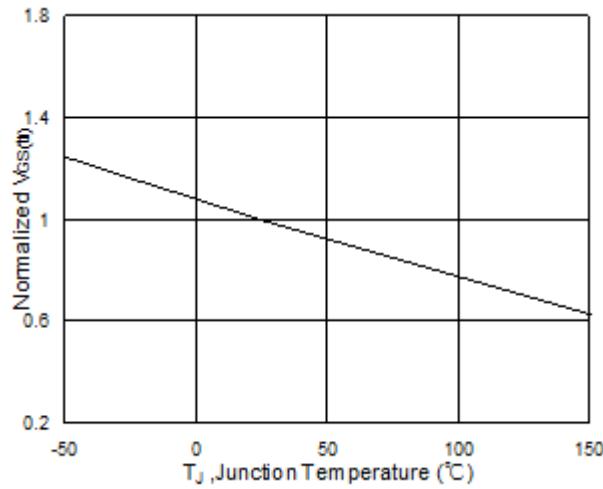


Fig.5 Normalized  $V_{GS(th)}$  vs  $T_J$

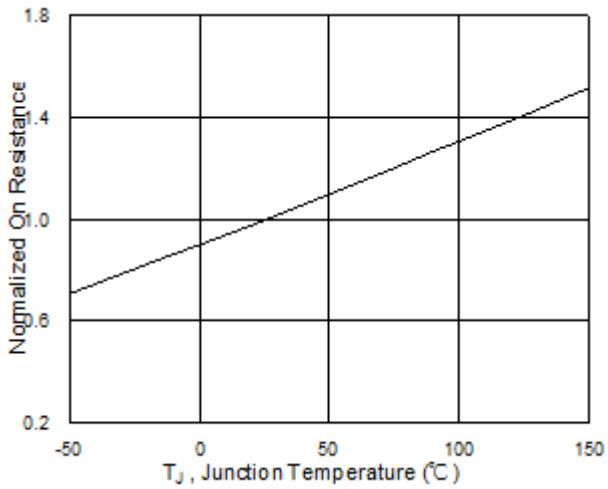
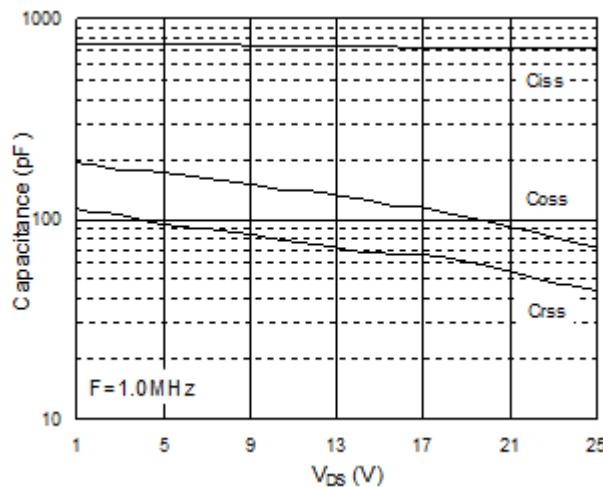
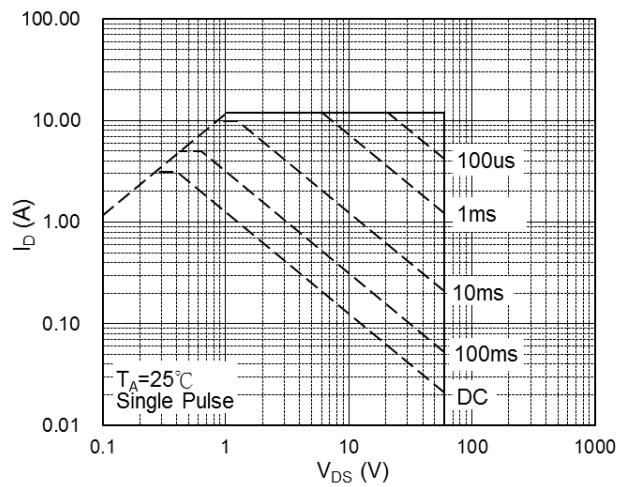


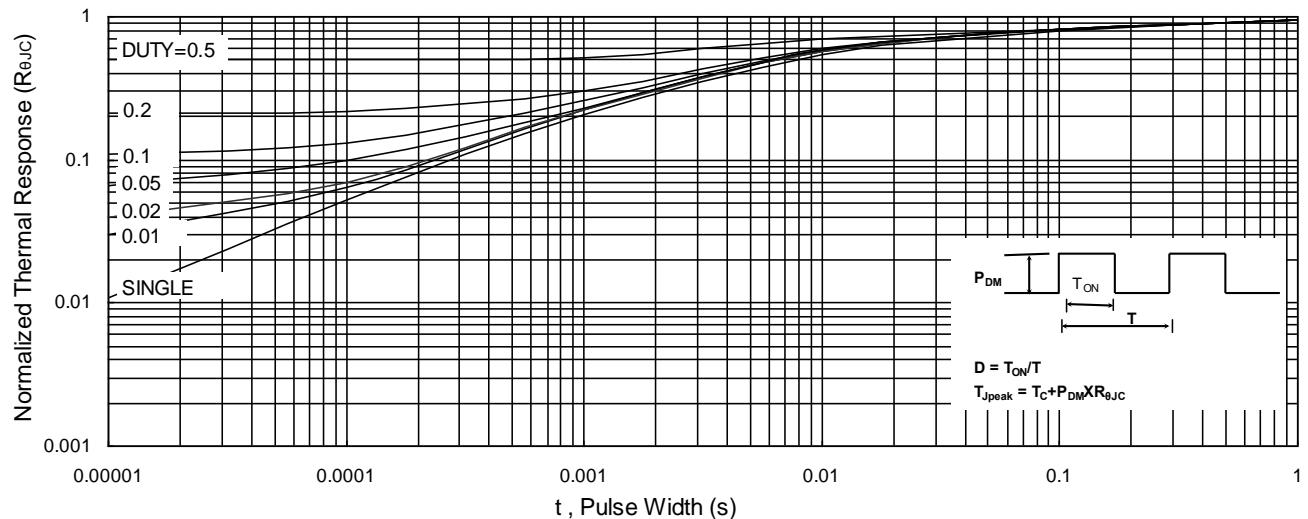
Fig.6 Normalized  $R_{DS(on)}$  vs  $T_J$



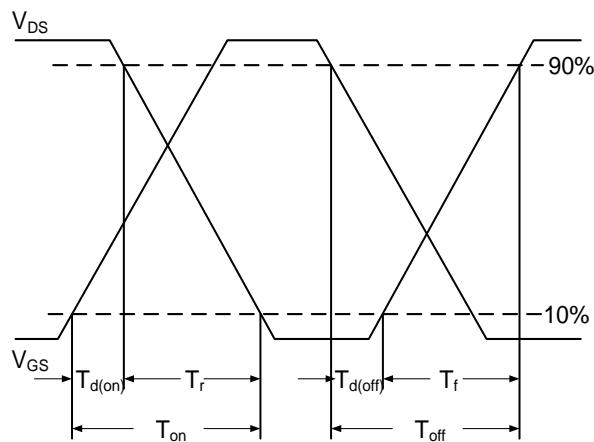
**Fig.7 Capacitance**



**Fig.8 Safe Operating Area**



**Fig.9 Normalized Maximum Transient Thermal Impedance**



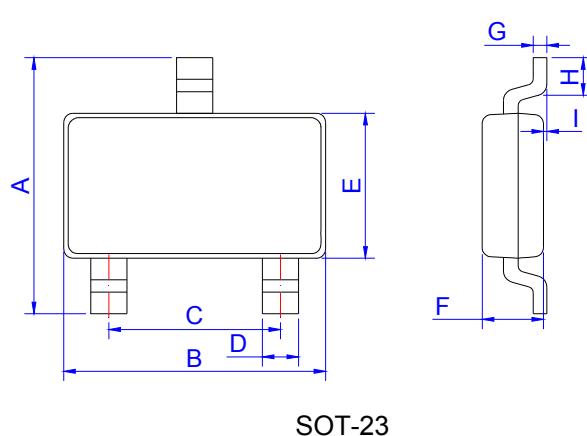
**Fig.10 Switching Time Waveform**

## Ordering and Marking Information

Ordering Device No	Marking	Package	Packing	Quantity
JME60N03ZA-R	60N03	SOT23	Tape&Reel	3000/Reel

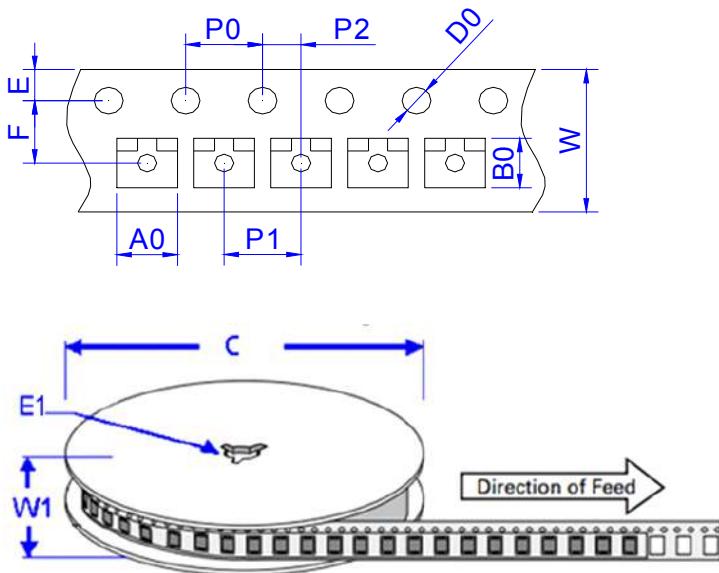
PACKAGE	MARKING
SOT23	<div style="border: 1px solid black; padding: 5px; text-align: center;">60N03</div>

## Package Mechanical Data



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.30	2.40	2.50	0.091	0.095	0.098
B	2.80	2.90	3.00	0.110	0.114	0.118
C	1.90 REF			0.075 REF		
D	0.35	0.40	0.45	0.014	0.016	0.018
E	1.20	1.30	1.40	0.047	0.051	0.055
F	0.90	1.00	1.10	0.035	0.039	0.043
G		0.10	0.15		0.004	0.006
H	0.20			0.008		
I	0		0.10	0		0.004

## Package Information-SOT23



Ref.	Dimensions	
	Millimeters	Inches
A0	3.15 ± 0.3	0.124 ± 0.012
B0	2.77 ± 0.3	0.109 ± 0.012
C	178	7.0
D0	1.50 ± 0.1	0.059 ± 0.004
E	1.75 ± 0.2	0.069 ± 0.008
E1	13.3 ± 0.3	0.524 ± 0.012
F	3.5 ± 0.2	0.138 ± 0.008
P0	4.00 ± 0.2	0.157 ± 0.008
P1	4.00 ± 0.2	0.157 ± 0.008
P2	2.00 ± 0.2	0.079 ± 0.008
W	8.00 ± 0.2	0.315 ± 0.008
W1	11.5 ± 1.0	0.453 ± 0.039

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